TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4075AP,TC74HC4075AF

Triple 3-Input OR Gate

The TC74HC4075A is a high speed CMOS 3-INPUT OR GATE fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

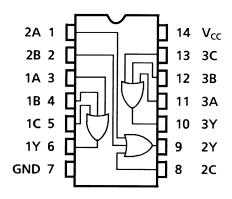
The internal circuit is composed of 4 stages including a buffered outputs, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

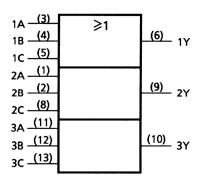
Features

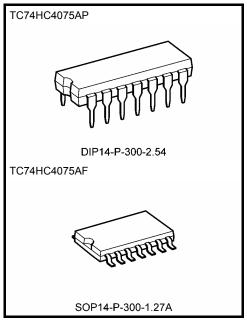
- High speed: $t_{pd} = 8 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 2 \mu A \text{ (max)}$ at $T_a = 25^{\circ}C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V
- Pin and function compatible with 4075B

Pin Assignment



IEC Logic Symbol





Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.)

Truth Table

| Α | В | С | Y |
|---|---|---|---|
| Н | Х | Х | Н |
| Х | Н | Х | Н |
| Х | Х | Н | Н |
| L | L | L | L |

X: Don't care

Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|------------------|-------------------------------|------|
| Supply voltage range | V _{CC} | –0.5 to 7 | V |
| DC input voltage | V _{IN} | −0.5 to V _{CC} + 0.5 | V |
| DC output voltage | V _{OUT} | -0.5 to V _{CC} + 0.5 | V |
| Input diode current | I _{IK} | ±20 | mA |
| Output diode current | lok | ±20 | mA |
| DC output current | lout | ±25 | mA |
| DC V _{CC} /ground current | I _{CC} | ±50 | mA |
| Power dissipation | PD | 500 (DIP) (Note 2)/180 (SOP) | mW |
| Storage temperature | T _{stg} | –65 to 150 | °C |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

| Characteristics | Symbol | Rating | Unit |
|--------------------------|---------------------------------|-------------------------------------|------|
| Supply voltage | V_{CC} | 2 to 6 | V |
| Input voltage | V _{IN} | 0 to V _{CC} | V |
| Output voltage | V _{OUT} | 0 to V _{CC} | V |
| Operating temperature | T _{opr} | −40 to 85 | °C |
| | | 0 to 1000 (V _{CC} = 2.0 V) | |
| Input rise and fall time | t _r , t _f | 0 to 500 (V _{CC} = 4.5 V) | ns |
| | | 0 to 400 (V _{CC} = 6.0 V) | |

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

| Characteristics Symbol | | Test Condition $V_{CC}\left(V\right)$ | | Ta = 25°C | | | Ta = -40 to 85°C | | Unit | |
|---------------------------|-----------------|---|----------------------------|---------------------|------|------|---------------------|------|------|----|
| | | | | V _{CC} (V) | Min | Тур. | Max | Min | Max | |
| | | _ | | 2.0 | 1.50 | _ | _ | 1.50 | _ | |
| High-level input voltage | V _{IH} | | | 4.5 | 3.15 | _ | _ | 3.15 | _ | V |
| Ţ. | | | | 6.0 | 4.20 | — | _ | 4.20 | — | |
| | | | | 2.0 | _ | _ | 0.50 | _ | 0.50 | |
| Low-level input voltage | V_{IL} | _ | | 4.5 | _ | _ | 1.35 | _ | 1.35 | V |
| Ţ. | | | | 6.0 | | — | 1.80 | _ | 1.80 | |
| | V _{ОН} | V _{IN} = V _{IH} or V _{IL} | | 2.0 | 1.9 | 2.0 | _ | 1.9 | _ | |
| | | | $I_{OH} = -20 \mu A$ | 4.5 | 4.4 | 4.5 | _ | 4.4 | _ | |
| High-level output voltage | | | | 6.0 | 5.9 | 6.0 | _ | 5.9 | — | V |
| | | | $I_{OH} = -4 \text{ mA}$ | 4.5 | 4.18 | 4.31 | _ | 4.13 | _ | |
| | | | $I_{OH} = -5.2 \text{ mA}$ | 6.0 | 5.68 | 5.80 | | 5.63 | _ | |
| | | V _{IN} = V _{IH} or V _{IL} | | 2.0 | | 0.0 | 0.1 | _ | 0.1 | |
| | | | $I_{OL} = 20 \mu A$ | 4.5 | _ | 0.0 | 0.1 | _ | 0.1 | |
| Low-level output voltage | V _{OL} | | | 6.0 | | 0.0 | 0.1 | | 0.1 | V |
| | | | I _{OL} = 4 mA | 4.5 | | 0.17 | 0.26 | _ | 0.33 | |
| | | | $I_{OL} = 5.2 \text{ mA}$ | 6.0 | _ | 0.18 | 0.26 | _ | 0.33 | |
| Input leakage current | I _{IN} | V _{IN} = V _{CC} or GND | | 6.0 | | _ | ±0.1 | | ±1.0 | μА |
| Quiescent supply current | I _{CC} | V _{IN} = V _{CC} or | GND | 6.0 | _ | _ | 1.0 | | 10.0 | μА |

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}\text{C}$, input: $t_r = t_f = 6 \text{ ns}$)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------|------------------|----------------|-----|------|-----|------|
| Output transition time | t _{TLH} | _ | _ | 4 | 8 | ns |
| | t _{THL} | | | | | |
| Propagation delay time | t _{pHL} | _ | | 8 | 15 | ns |

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AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

| Characteristics | Symbol | Test Condition | | Ta = 25°C | | | Ta = -40 to 85°C | | Unit |
|-------------------------------|------------------|----------------|---------------------|-----------|------|-----|---------------------|-----|------|
| | - , | | V _{CC} (V) | Min | Тур. | Max | Min | Max | |
| | 4 — | | 2.0 | _ | 30 | 75 | _ | 95 | |
| Output transition time | t _{TLH} | _ | 4.5 | _ | 8 | 15 | _ | 19 | ns |
| | t _{THL} | | 6.0 | _ | 7 | 13 | _ | 16 | |
| | t _{pLH} | _ | 2.0 | _ | 35 | 90 | _ | 115 | |
| Propagation delay time | | | 4.5 | _ | 11 | 18 | _ | 23 | ns |
| | t _{pHL} | | 6.0 | _ | 9 | 15 | _ | 20 | |
| Input capacitance | C _{IN} | _ | | _ | 5 | 10 | _ | 10 | pF |
| Power dissipation capacitance | C _{PD} | | | _ | 27 | _ | _ | _ | pΕ |
| | (Note) | _ | | | | | | | pF |

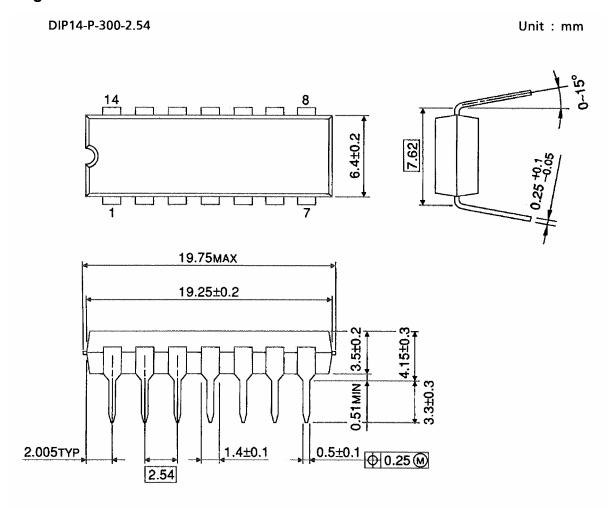
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$ (per gate)



Package Dimensions



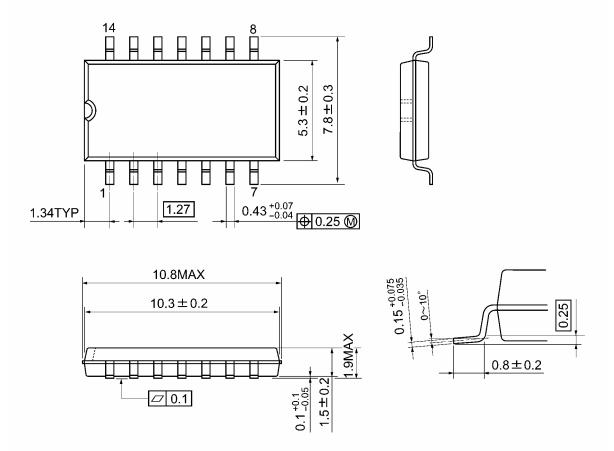
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Weight: 0.96 g (typ.)



Package Dimensions

SOP14-P-300-1.27A Unit: mm



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Weight: 0.18 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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